

PJQ45816P-AU

80V N-Channel Enhancement Mode MOSFET

Voltage

80 V

Current

33 A

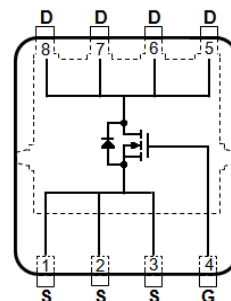
Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@8A<23.5m\Omega$
- $R_{DS(ON)}$, $V_{GS}@7V$, $I_D@4A<30.5m\Omega$
- Excellent FOM
- Standard Level Drive
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.03 grams

DFN3333-8L



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	80	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current ^(Note 3)	$T_C=25^{\circ}C$	I_D	33	A
	$T_C=100^{\circ}C$		23	
Pulsed Drain Current ^(Note 1)	$T_C=25^{\circ}C$	I_{DM}	80	
Power Dissipation	$T_C=25^{\circ}C$	P_D	50	W
	$T_C=100^{\circ}C$		25	
Continuous Drain Current ^(Note 4)	$T_A=25^{\circ}C$	I_D	8.4	A
	$T_A=70^{\circ}C$		7.0	
Power Dissipation	$T_A=25^{\circ}C$	P_D	3.3	W
	$T_A=70^{\circ}C$		2.3	
Single Pulse Avalanche Current ^(Note 5)		I_{AS}	6	A
Single Pulse Avalanche Energy ^(Note 5)		E_{AS}	16	mJ
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~175	$^{\circ}C$
Thermal Resistance ^(Note 4)	Junction to Case	$R_{\theta JC}$	3	$^{\circ}C/W$
	Junction to Ambient	$R_{\theta JA}$	45	

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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	80	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	2	-	3.8	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =8A	-	19	23.5	mΩ
		V _{GS} =7V, I _D =4A	-	23.2	30.5	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =80V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic ^(Note 6)						
Total Gate Charge	Q _g	V _{DS} =40V, I _D =15A, V _{GS} =10V ^(Note 2)	-	6.7	9	nC
Gate-Source Charge	Q _{gs}		-	2.7	-	
Gate-Drain Charge	Q _{gd}		-	1.2	-	
Input Capacitance	C _{iss}	V _{DS} =40V, V _{GS} =0V, f=1MHz	-	373	559	pF
Output Capacitance	C _{oss}		-	178	267	
Reverse Transfer Capacitance	C _{rss}		-	6	11	
Gate resistance	R _g	f=1MHz	-	1.1	2.2	Ω
Turn-On Delay Time	td _(on)	V _{DS} =40V, I _D =15A, V _{GS} =10V, R _G =2.5Ω ^(Note 2)	-	5.8	-	ns
Turn-On Rise Time	tr		-	1.6	-	
Turn-Off Delay Time	td _(off)		-	8.1	-	
Turn-Off Fall Time	tf		-	2.1	-	
Drain-Source Diode						
Diode Forward Current	I _s	T _C =25° C (Package Limit)	-	-	33	A
Pulsed Diode Forward Current	I _{SM}		-	-	80	
Diode Forward Voltage	V _{SD}	I _S =8A, V _{GS} =0V	-	0.9	1.2	V
Reverse Recovery Time	T _{rr}	V _{DD} =40V V _{GS} =0V,	-	22.6	-	ns
Reverse Recovery Charge	Q _{rr}	I _S =15A, dI _S /dt=100A/us	-	15.8	-	nC

NOTES :

1. Pulse width≤100us, Duty cycle≤2%.
2. Essentially independent of operating temperature typical characteristics.
3. Chip capability with an R_{θJC}=3°C/W.
4. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
5. E_{AS} is calculated based on the condition of L=1mH, I_{AS}=5.6A, V_{DD}=30V, V_{GS}=10V. 100% test at L=0.5mH, I_{AS}=6A in production.
6. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

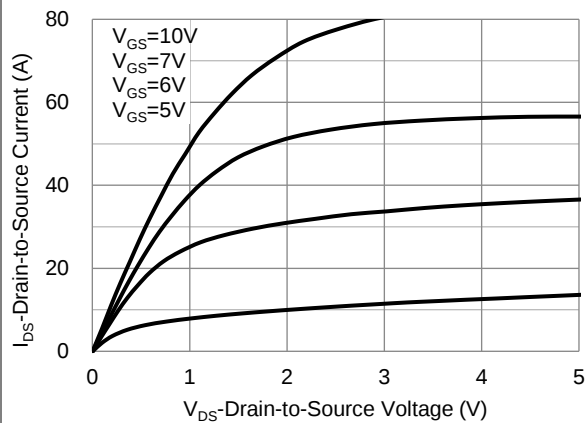


Fig.1 On-Region Characteristics

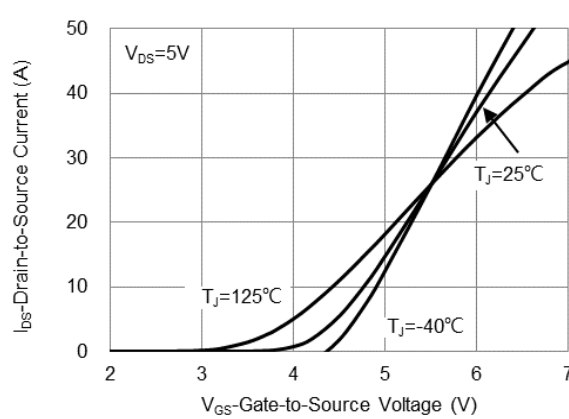


Fig.2 Transfer Characteristics

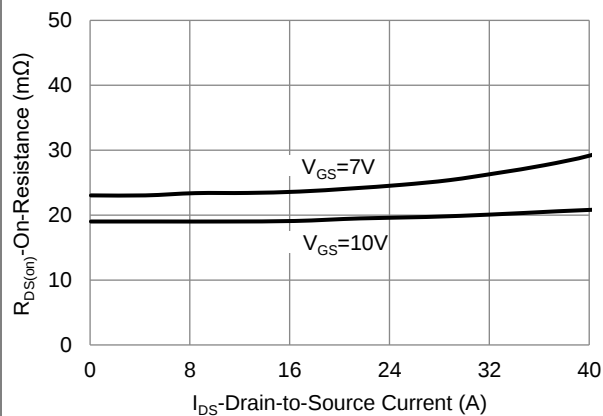


Fig.3 On-Resistance vs. Drain Current

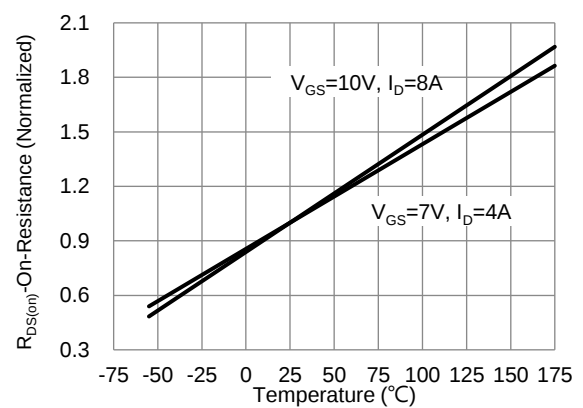


Fig.4 On-Resistance vs. Junction temperature

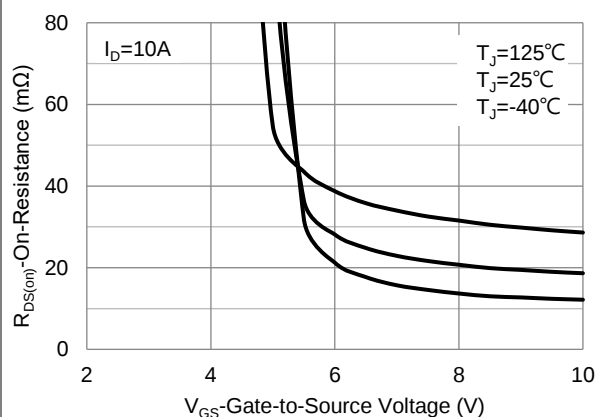


Fig.5 On-Resistance Variation with V_{GS}

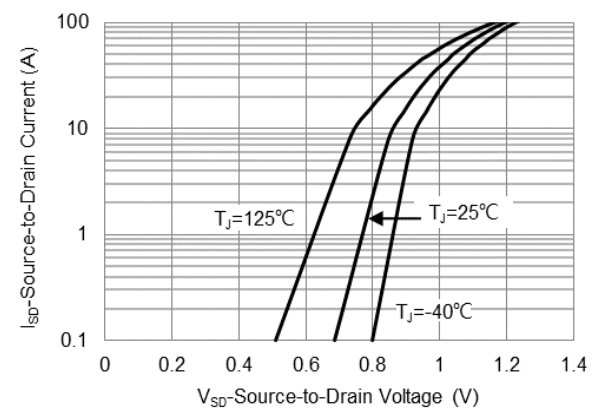
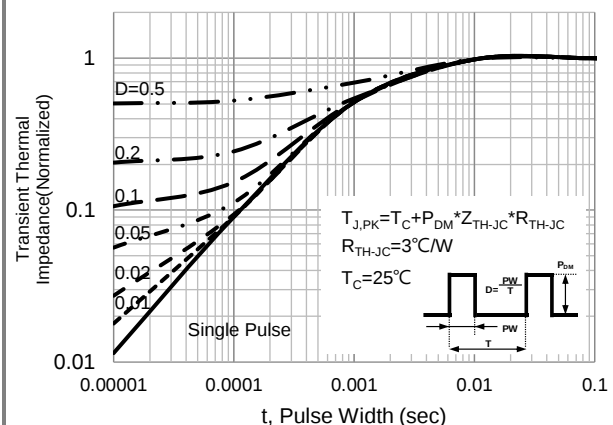
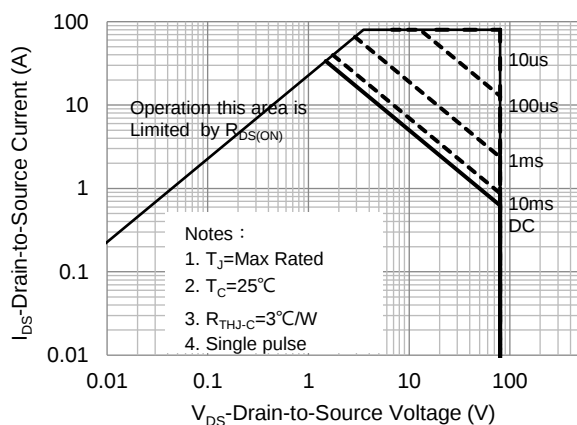
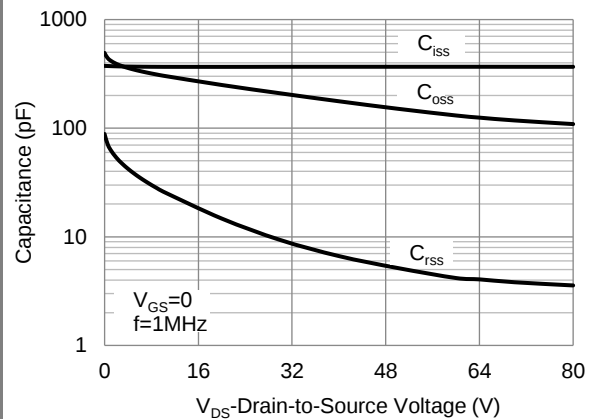
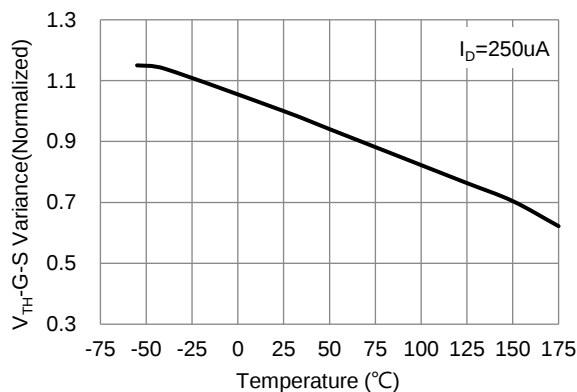
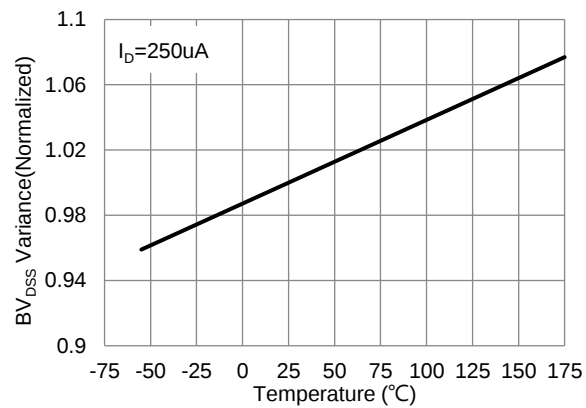
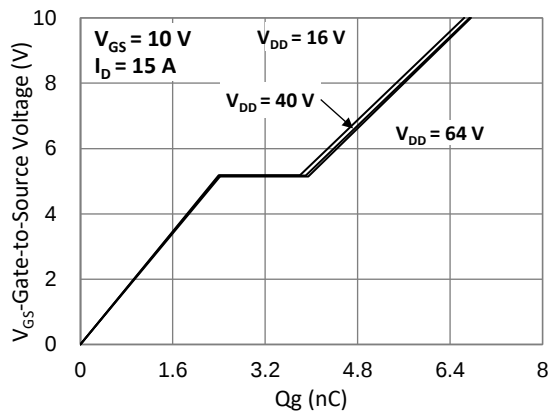


Fig.6 Source-Drain Diode Forward Voltage

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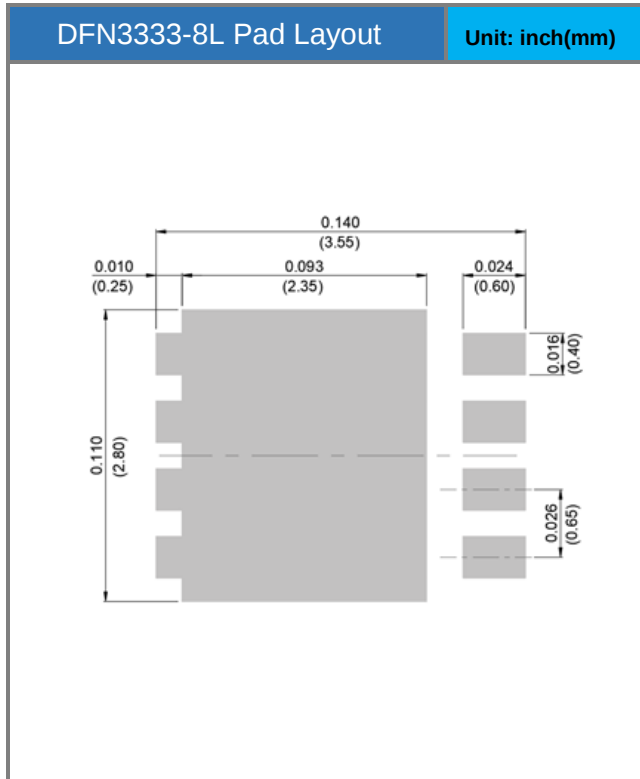
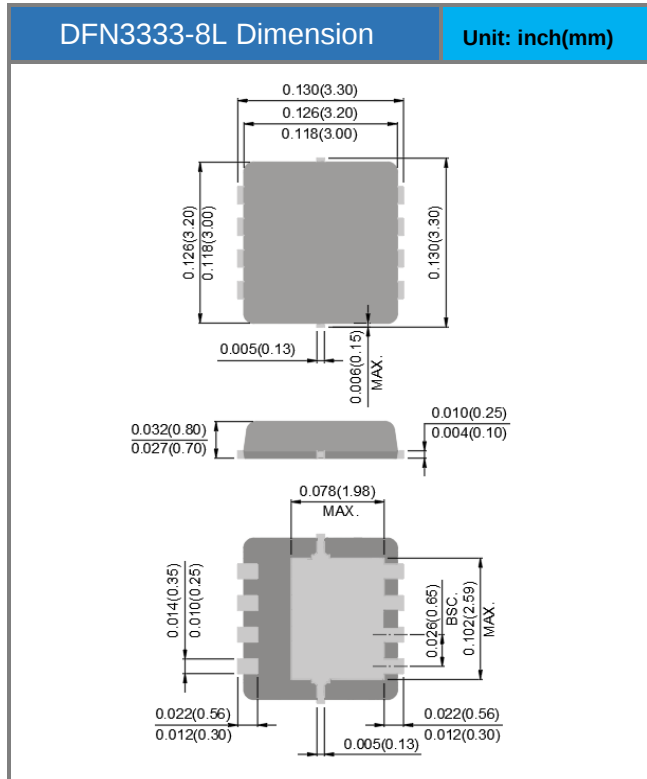


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Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJQ45816P-AU	DFN3333-8L	5K pcs / 13" reel	45816

Packaging Information & Mounting Pad Layout



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